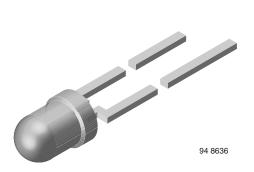
Vishay Semiconductors

Infrared Emitting Diode, 875 nm, GaAlAs



www.vishay.com

DESCRIPTION

The TSHA440. series are infrared, 875 nm emitting diodes in GaAlAs technology, molded in a clear, untinted plastic package.

FEATURES

- · Package type: leaded
- Package form: T-1
- Dimensions (in mm): Ø 3
- Peak wavelength: λ_p = 875 nm
- High reliability
- Angle of half intensity: $\phi = \pm 20^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- Infrared remote control and free air data transmission systems with comfortable radiation angle
- This emitter series is dedicated to systems with panes in transmission space between emitter and detector, because of the low absorption of 875 nm radiation in glass

PRODUCT SUMMARY

COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)		
TSHA4400	20	± 20	875	600		
TSHA4401	30	± 20	875	600		

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSHA4400	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1		
TSHA4401	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1		

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V _R	5	V		
Forward current		I _F	100	mA		
Peak forward current	t _p /T = 0.5, t _p = 100 μs	I _{FM}	200	mA		
Surge forward current	t _p = 100 μs	I _{FSM}	2	А		
Power dissipation		Pv	180	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T _{amb}	-40 to +85	°C		
Storage temperature range		T _{stg}	-40 to +100	°C		
Soldering temperature	$t \leq 5$ s, 2 mm from case	T _{sd}	260	°C		
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	300	K/W		

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RoHS

COMPLIANT

HALOGEN

<u>GREEN</u>

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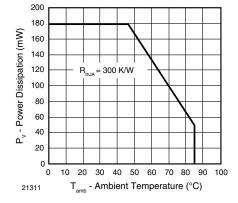


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

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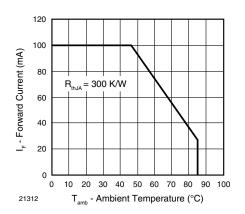


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.5	1.8	V
Forward voltage	$I_F = 1.5 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		3.2	4.9	V
Temperature coefficient of V _F	l _F = 100 mA	TK _{VF}		-1.6		mV/K
Reverse current	V _R = 5 V	I _R			100	μA
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		20		pF
Temperature coefficient of ϕ_{e}	l _F = 100 mA	TKφ _e		-0.7		%/K
Angle of half intensity		φ		± 20		deg
Peak wavelength	l _F = 100 mA	λρ		875		nm
Spectral bandwidth	l _F = 100 mA	Δλ		80		nm
Temperature coefficient of λ_p	l _F = 100 mA	ΤΚλρ		0.2		nm/K
Rise time	l _F = 100 mA	t _r		600		ns
Rise time	I _F = 1.5 A t _r 300	300		ns		
Fall time	I _F = 100 mA		ns			
	I _F = 1.5 A	t _f		300		ns
Virtual source diameter		d		1.8		mm

TYPE DEDICATED CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$1 - 100 m \Lambda + - 20 m \Lambda$	TSHA4400	l _e	12	20	60	mW/sr mW/sr mW/sr mW/sr mW
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TSHA4401	l _e	16	30	60	
natiant intensity	1 - 15 m A + - 100 u a	TSHA4400	l _e	140	240		mW/sr
	I _F = 1.5 mA, t _p = 100 μs	TSHA4401	l _e	190	360		mW/sr
Radiant power	I _F = 100 mA, t _p = 20 ms	TSHA4400	фе		20		mW
	$r_F = 100 \text{ mA}, r_p = 20 \text{ ms}$	TSHA4401	фе		24		mW



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

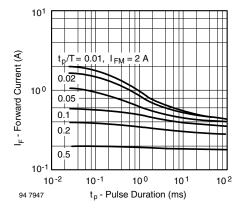


Fig. 3 - Pulse Forward Current vs. Pulse Duration

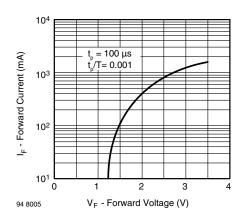


Fig. 4 - Forward Current vs. Forward Voltage

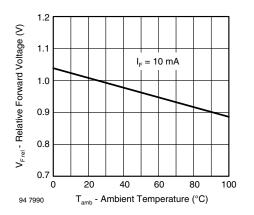


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

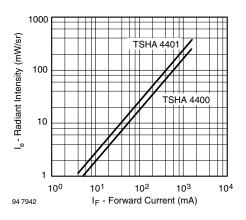


Fig. 6 - Radiant Intensity vs. Forward Current

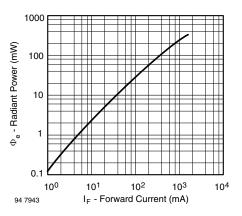


Fig. 7 - Radiant Power vs. Forward Current

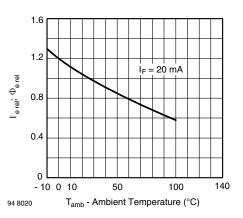


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature

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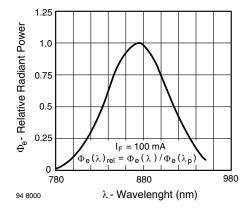
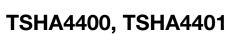


Fig. 9 - Relative Radiant Power vs. Wavelength

PACKAGE DIMENSIONS in millimeters



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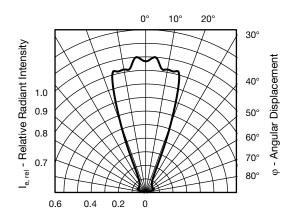
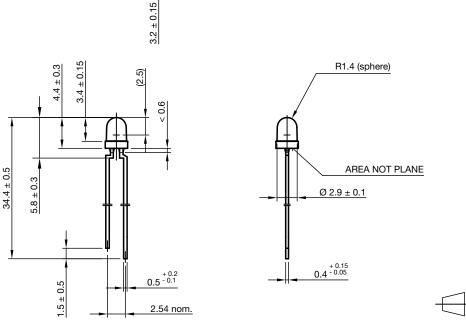


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement



technical drawings according to DIN specifications

Drawing-No.: 6.544-5264.01-4 Issue: 4; 28.07.14

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